



45V NPN SMALL SIGNAL TRANSISTOR IN SOT523

Description

This Bipolar Junction Transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

Features

- BV_{CEO} > 45V
- I_C = 100mA Collector Current
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT523
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.002 grams (Approximate)

SOT523



Top View



Device Symbol



Pin-Out Top View

Ordering Information (Note 5)

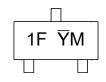
ĺ	Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
	BC847BTQ-7	Automotive	1F	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information

SOT523



 $\begin{array}{l} 1F = Product\ Type\ Marking\ Code \\ \hline YM = Date\ Code\ Marking \\ Y\ or\ \overline{Y} = Year\ (ex:\ G=2019) \\ M\ or\ \overline{M} = Month\ (ex:\ 9=September) \end{array}$

Date Code Key

Year	2019	9	2020	2021	2022	2023	2024	202	5 20	26 2	2027	2028	2029
Code	G		Н		J	K	L	М	1	٧	0	Р	Q
Monti	h	Jar	n Fel	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code		1	2	3	4	5	6	7	8	9	0	N	D



Absolute Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	50	V
Collector-Emitter Voltage	$V_{\sf CEO}$	45	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Collector Current	lc	100	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P_{D}	150	mW
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	833	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

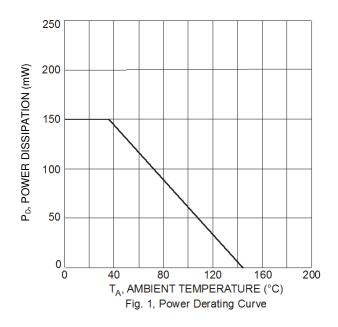
ESD Ratings (Note 7)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes:

- 6. For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state. 7. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information





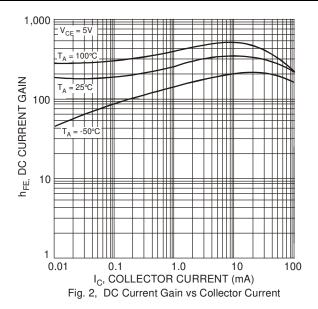
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						•
Collector-Base Breakdown Voltage	BV _{CBO}	50			V	$I_C = 10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	BV _{CEO}	45	_	_	V	$I_C = 1 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage	BV _{EBO}	6.0	_	_	V	$I_E = 10 \mu A, I_C = 0$
ON CHARACTERISTICS (Note 8)				•	•	•
DC Current Gain	h _{FE}	200	290	450	_	$V_{CE} = 5.0V, I_{C} = 2.0mA$
Collector-Emitter Saturation Voltage	Variour		_	250	mV	$I_C = 10mA$, $I_B = 0.5mA$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_		600		$I_C = 100 \text{mA}, I_B = 5 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	700		mV	$I_C = 10mA$, $I_B = 0.5mA$
Dase-Emiller Saturation Voltage			900	_		$I_C = 100 \text{mA}, I_B = 5 \text{mA}$
Base-Emitter Turn-On Voltage	V _{BE(ON)}	580	660	700	mV	$V_{CE} = 5.0V, I_{C} = 2.0mA$
Base-Emiller rum-On voltage		_	_	770	111 V	$V_{CE} = 5.0V, I_{C} = 10mA$
Collector-Emitter Cutoff Current	1			15	nA	$V_{CB} = 30V$
Conector-Emitter Cuton Current	I _{CBO}		_	5.0	μΑ	$V_{CB} = 30V, T_A = +150$ °C
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C _{OBO}	_		4.5	pF	$V_{CB} = 10V, f = 1.0MHz$
Current Gain-Bandwidth Product	f _T	100	_		MHz	$V_{CE} = 5V$, $I_{C} = 10mA$, $f = 100MHz$
Noise Figure	NF	_	_	1.0	dB	$V_{CE} = 5V$, $R_S = 2k\Omega$, $f = 1MHz$, $BW = 200Hz$

Note: 8. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



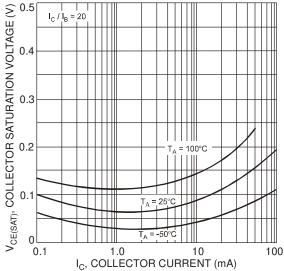


Fig. 3, Collector Saturation Voltage vs Collector Current

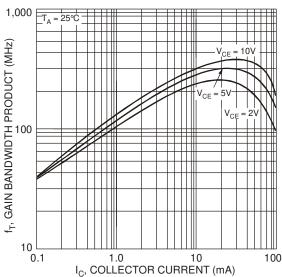


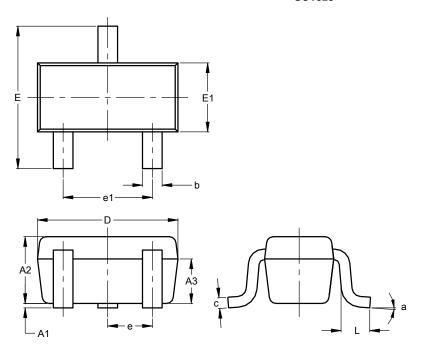
Fig. 4, Gain Bandwidth Product vs Collector Current



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

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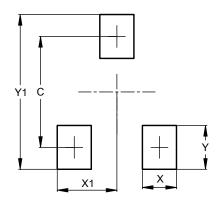


)T523					
Dim	Min	Max	Тур				
A 1	0.00	0.10	0.05				
A2	0.60	0.80	0.75				
A 3	0.45	0.65	0.50				
b	0.15	0.30	0.22				
O	0.10	0.20	0.12				
D	1.50	1.70	1.60				
Е	1.45	1.75	1.60				
E1	0.75	0.85	0.80				
е		0.50 BS	С				
e1	0.90	1.10	1.00				
L	0.20	0.40	0.33				
а	0°	_	8°				
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT523



Dimensions	Value (in mm)
C	1.29
Х	0.40
X1	0.70
Y	0.51
V1	1.80



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